

## PNP SILICON SMALL SIGNAL TRANSISTOR

Qualified per MIL-PRF-19500/382

### Devices

2N2944A

2N2945A

2N2946A

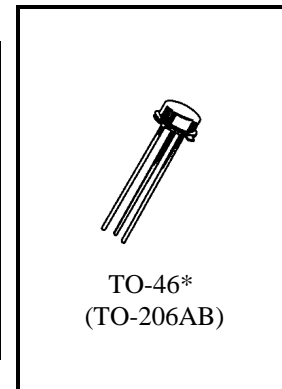
### Qualified Level

JAN  
JANTX  
JANTV

### MAXIMUM RATINGS

Ratings	Sym	2N2944A	2N2945A	2N2946A	Unit
Collector-Emitter Voltage	$V_{CEO}$	10	20	35	Vdc
Emitter-Collector Voltage	$V_{ECO}$	10	20	35	Vdc
Collector-Base Voltage	$V_{CBO}$	15	25	40	Vdc
Emitter-Base Voltage	$V_{EBO}$	15	25	40	Vdc
Collector Current	$I_C$	100			mAdc
Total Power Dissipation @ $T_A = +25^{\circ}\text{C}$	$P_T^{(1)}$	400			mW
Operating & Storage Junction Temperature Range	$T_J, T_{stg}$	-65 to +200			$^{\circ}\text{C}$

1) Derate linearly 2.30 mW/ $^{\circ}\text{C}$  above  $T_A = +25^{\circ}\text{C}$



\*See appendix A for package outline

### ELECTRICAL CHARACTERISTICS ( $T_A = 25^{\circ}\text{C}$ unless otherwise noted)

Characteristics	Symbol	Min.	Max.	Unit
<b>OFF CHARACTERISTICS</b>				
Collector-Emitter Breakdown Voltage $I_C = 10 \mu\text{Adc}$	$V_{(BR)CEO}$	10		Vdc
2N2944A		20		
2N2945A 2N2946A		35		
Emitter-Collector Breakdown Voltage $I_E = 10 \mu\text{Adc}$	$V_{(BR)ECO}$	10		Vdc
2N2944A		20		
2N2945A 2N2946A		35		
Collector-Base Cutoff Current $I_C = 10 \mu\text{Adc}, V_{CB} = -15 \text{Vdc}$	$I_{CBO}$	10		$\mu\text{Adc}$
$I_C = 10 \mu\text{Adc}, V_{CB} = -25 \text{Vdc}$		10		$\mu\text{Adc}$
$I_C = 10 \mu\text{Adc}, V_{CB} = -40 \text{Vdc}$		10		$\mu\text{Adc}$

**2N2944A, 2N2945A, 2N2946A JAN SERIES**

**ELECTRICAL CHARACTERISTICS (con't)**

Characteristics	Symbol	Min.	Max.	Unit
Emitter-Base Cutoff Current				
$V_{EB} = 15 \text{ Vdc}$ 2N2944A	$I_{EBO}$		0.1	$\eta\text{Adc}$
$V_{EB} = 25 \text{ Vdc}$ 2N2945A		0.2		
$V_{EB} = 40 \text{ Vdc}$ 2N2946A		0.5		

**ON CHARACTERISTICS <sup>(2)</sup>**

Forward-Current Transfer Ratio				
$I_C = 1.0 \text{ mAdc}, V_{CE} = 0.5 \text{ Vdc}$ 2N2944A 2N2945A 2N2946A	$h_{FE}$	100 70 50		
Forward-Current Transfer Ratio				
$I_B = 200 \mu\text{Adc}, V_{EC} = -0.5 \text{ Vdc}$ 2N2944A 2N2945A 2N2946A		$h_{FE(INV)}$	50 30 20	
Emitter-Collector Offset Voltage				
$I_B = 200 \mu\text{Adc}, I_E = 0$ 2N2944A 2N2945A 2N2946A	$V_{EC(OFS)}$			0.3 0.5 0.8
$I_B = 1.0 \text{ mAdc}, I_E = 0$ 2N2944A 2N2945A 2N2946A		0.6 1.0 2.0		
$I_B = 2.0 \text{ mAdc}, I_E = 0$ 2N2944A 2N2945A 2N2946A		1.0 1.6 2.5		

**DYNAMIC CHARACTERISTICS**

Emitter-Collector On-State Resistance				
$I_B = 100 \mu\text{Adc}, I_E = 0, I_c = 100 \mu\text{Adc (rms)}$ $f = 1.0 \text{ kHz}$ 2N2944A 2N2945A 2N2946A	$r_{ec(on)}$		10 12 14	$\Omega$
$I_B = 1.0 \text{ mAdc}, I_E = 0, I_c = 100 \mu\text{Adc (rms)}$ $f = 1.0 \text{ kHz}$ 2N2944A 2N2945A 2N2946A		4.0 6.0 8.0		
Magnitude of Small-Signal Forward Current Transfer Ratio				
$I_C = 1.0 \text{ mAdc}, V_{CE} = 6.0\text{Vdc}, f = 1.0 \text{ MHz}$ 2N2944A 2N2945A 2N2946A	$h_{fe}$	15 10 5.0	55 55 55	
Output Capacitance				
$V_{CB} = 6.0 \text{ Vdc}, I_E = 0, 100 \text{ kHz} \leq f \leq 1.0 \text{ MHz}$		$C_{obo}$		10
Input Capacitance				
$V_{EB} = 6.0 \text{ Vdc}, I_C = 0, 100 \text{ kHz} \leq f \leq 1.0 \text{ MHz}$	$C_{ibo}$		6.0	$\text{pF}$

(2) Pulse Test: Pulse Width = 300 $\mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .